Cascadable Silicon Bipolar MMIC Amplifier

Technical Data

Features

- Cascadable 50 Ω Gain Block
- High Output Power: 18.0 dBm Typical P_{1 dB} at 1.0 GHz
- Low Distortion: 29.0 dBm Typical IP₃ at 1.0 GHz
- 7.0 dB Typical Gain at 1.0 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available^[1]

Note:

1. Refer to PACKAGING section "Tape-and-Reel Packaging for Semiconductor Devices."

Description

The MSA-0505 is a high performance medium power silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount package. This MMIC is designed for use as a general purpose 50 Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial systems.

The MSA-series is fabricated using HP's 10 GHz f_T , 25 GHz f_{MAX} , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

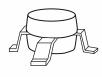
MSA-0505

专业PCB打样工

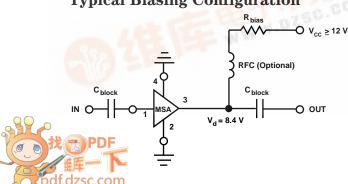
24小时加急出货

HEWI ETT

05 Plastic Package



Typical Biasing Configuration



MSA-0505 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]				
Device Current	135 mA				
Power Dissipation ^[2,3]	1.5W				
RF Input Power	+25 dBm				
Junction Temperature	200°C				
Storage Temperature	-65 to 150°C				

Thermal Resistance^[2,4]: $\theta_{jc} = 85^{\circ}C/W$

Notes:

- Permanent damage may occur if any of these limits are exceeded.
 T = 25%C
- 2. $T_{CASE} = 25$ °C.
- 3. Derate at 11.8 mW/°C for $T_{\rm C}>73^{\circ}{\rm C}.$
- 4. See MEASUREMENTS section "Thermal Resistance" for more information.

Symbol	Parameters and Test Conditions:	Units	Min.	Тур.	Max.	
P_{1dB}	Output Power at 1 dB Gain Compression	f = 0.5 GHz $f = 1.0 GHz$	dBm dBm	16.0	19.0 18.0	
GP	Power Gain $(S_{21} ^2)$	f = 0.5 GHz $f = 1.0 GHz$	dB	6.0	7.5 7.0	
ΔG_P	Gain Flatness	f = 0.1 to 1.5 GHz	dB		± 0.75	
f3 dB	3 dB Bandwidth ^[2]		GHz		2.3	
VSWR	Input VSWR	f = 0.1 to 1.5 GHz			1.6:1	
	Output VSWR	f = 0.1 to 1.5 GHz			2.0:1	
IP ₃	Third Order Intercept Point	f = 1.0 GHz	dBm		29.0	
NF	50Ω Noise Figure	f = 1.0 GHz	dB		6.5	
$t_{\rm D}$	Group Delay	f = 1.0 GHz	psec		190	
Vd	Device Voltage		V	6.7	8.4	10.1
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-16.0	

Electrical Specifications^[1], $T_A = 25^{\circ}C$

Notes:

1. The recommended operating current range for this device is 60 to 100 mA. Typical performance as a function of current is on the following page.

2. Referenced from 0.1 GHz Gain (G_P).

Part Number Ordering Information

Part Number	No. of Devices	Container		
MSA-0505-TR1	500	7" Reel		
MSA-0505-STR	10	Strip		

For more information, see "Tape and Reel Packaging for Semiconductor Devices".

Freq.	Freq. S ₁₁		S ₂₁		\mathbf{S}_{12}			\mathbf{S}_{22}			
MHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	k
5	.56	-39	14.9	5.56	161	-18.5	.120	39	.65	-36	0.60
25	.24	-103	9.7	3.05	156	-13.9	.202	12	.25	-90	0.97
50	.15	-130	8.2	2.57	163	-13.7	.207	7	.15	-116	1.15
100	.13	-155	7.8	2.45	165	-13.7	.207	3	.11	-132	1.21
200	.12	-170	7.7	3.43	161	-13.5	.211	1	.11	-145	1.21
400	.12	178	7.5	2.37	148	-13.6	.209	-1	.14	-146	1.23
600	.13	172	7.4	2.34	134	-13.6	.209	-2	.17	-151	1.23
800	.13	168	7.2	2.29	119	-13.6	.209	-3	.21	-157	1.23
1000	.14	166	7.0	2.24	105	-13.4	.213	-4	.25	-164	1.21
1500	.21	159	6.4	2.09	72	-13.3	.217	-6	.34	176	1.16
2000	.30	148	5.2	1.82	42	-13.1	.222	-9	.42	159	1.12
2500	.40	136	4.1	1.60	17	-12.9	.227	-11	.48	146	1.05
3000	.52	121	2.7	1.36	-7	-12.6	.234	-16	.55	133	0.92

MSA-0505 Typical Scattering Parameters (T_A = 25 °C, I_d = 80 mA)

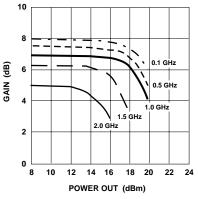
A model for this device is available in the DEVICE MODELS section.

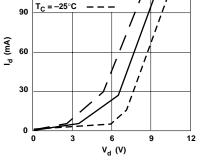
120

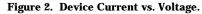
T_C = +85°C T_C = +25°C

Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)







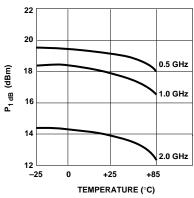
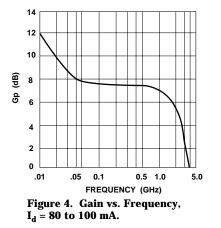


Figure 3. Output Power at 1 dB Gain Compression, vs. Case Temperature, $I_d = 80$ mA.

Figure 1. Typical Gain vs. Power Out, T_A = 25°C, I_d = 80 mA.



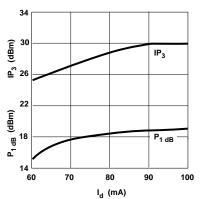
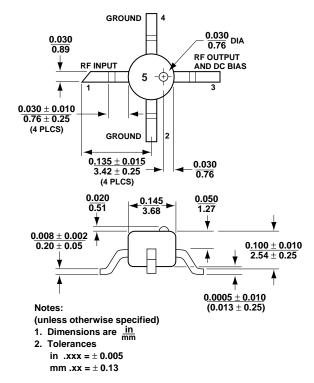


Figure 5. Output Power at 1 dB Gain Compression, Third Order Intercept vs. Case Temperature, f = 1.0 GHz.



05 Plastic Package Dimensions